

Strong spin-phonon coupling in infrared and Raman spectra of SrMnO₃S. Kamba,^{1,*} V. Goian,¹ V. Skoromets,¹ J. Hejtmánek,¹ V. Bovtun,¹ M. Kempa,¹ F. Borodavka,¹ P. Vaněk,¹ A. A. Belik,² J. H. Lee,³ O. Pacherová,¹ and K. M. Rabe³¹*Institute of Physics ASCR, Na Slovance 2, 182 21 Prague 8, Czech Republic*²*International Center for Materials Nanoarchitectonics (WPI-MANA), National Institute for Materials Science (NIMS), 1-1 Namiki, Tsukuba, Ibaraki 305-0044, Japan*³*Department of Physics and Astronomy, Rutgers University, Piscataway, New Jersey 08854-8019, USA*
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Infrared reflectivity spectra of cubic SrMnO₃ ceramics reveal 18% stiffening of the lowest-frequency phonon below the antiferromagnetic phase transition occurring at $T_N = 233$ K. Such a large temperature change of the polar phonon frequency is extraordinary and we attribute it to an exceptionally strong spin-phonon coupling in this material. This is consistent with our prediction from first-principles calculations. Moreover, polar phonons become Raman active below T_N , although their activation is forbidden by symmetry in the $Pm\bar{3}m$ space group. This gives evidence that the cubic $Pm\bar{3}m$ symmetry is locally broken below T_N due to a strong magnetoelectric coupling. Multiphonon and multimagnon scattering is also observed in Raman spectra. Microwave and THz permittivity is strongly influenced by hopping electronic conductivity, which is caused by small nonstoichiometry of the sample. Thermoelectric measurements show room-temperature concentration of free carriers $n_e = 3.6 \times 10^{20} \text{ cm}^{-3}$ and the sample composition Sr²⁺Mn_{0.98}⁴⁺Mn_{0.02}³⁺O_{2.99}⁻. The conductivity exhibits very unusual temperature behavior: THz conductivity increases on cooling, while the static conductivity markedly decreases on cooling. We attribute this to different conductivity of the ceramic grains and grain boundaries.

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I. INTRODUCTION

In the last decade, there has been an intensive search for new multiferroic materials, in particular those exhibiting ferroelectric (FE) and ferromagnetic (FM) order. The aim is to find multiferroics with a large magnetoelectric coupling, which could allow the control of magnetization by external electric field. Such materials could be used in future electronic devices including nonvolatile memories and spin filters. Unfortunately, most multiferroics exhibit antiferromagnetic (AFM) order with a weak magnetoelectric coupling or low critical temperatures, and thus they are not suitable for practical applications.

One mechanism that has been demonstrated to produce novel multiferroics is application of an epitaxial strain (or a comparable perturbation) to an AFM paraelectric material with a large spin-phonon coupling such that the lowest frequency polar phonon with hypothetical ferromagnetic (FM) ordering has lower frequency than the corresponding phonon in the AFM phase. Lowering of the polar phonon frequency by the strain can produce a polar instability in the FM phase, with the resulting energy lowering, which stabilizes a FE-FM multiferroic phase over the bulk AFM paraelectric phase [1]. This has been experimentally confirmed in EuTiO₃ with a magnetic ordering temperature of 5.3 K [2].

Recently, Lee and Rabe showed using first-principles calculations that this mechanism would produce a multiferroic phase in SrMnO₃ [3]. Since bulk SrMnO₃ is AFM below $T_N = 230$ K [4], strained thin films should be FM with critical temperatures above 100 or 150 K [3]. However, due to the very high critical strain (3.6%), experimental efforts to realize this phase have been so far unsuccessful. Tuning

of the polar phonons by a related but different perturbation, negative chemical pressure through continuous substitution of Sr by Ba, has recently been investigated. Sakai *et al.* [5,6] observed ferroelectricity below 410 K in Sr_{1-x}Ba_xMnO₃ single crystals with $0.45 \leq x \leq 0.50$. The polar distortion is found to be dominated by displacement of magnetic Mn⁴⁺ cations (running counter to the conventional expectation that *d* electrons inhibit off-centering of the cations [7]) and therefore the magnetoelectric coupling is the largest attained so far [5]. However, the magnetic ordering for the ferroelectric phase is G-type AFM, so that ferroelectricity is the result of destabilization of the polar mode by strain within the original AFM phase, and the system is not a true (FM-FE) multiferroic.

The prospects for stabilizing a true multiferroic in SrMnO₃ or related compounds hinge on better knowledge and control of the spin-phonon coupling. Fortunately, the spin-phonon coupling can be directly investigated experimentally. Specifically, this coupling should result in a remarkable stiffening of the Slater-type (i.e., vibration of Mn cations against oxygen octahedra) mode frequency near and below T_N [8]. Indeed, unusually large shifts in phonon frequency at T_N have recently been observed in Sr_{1-x}Ba_xMnO₃ for $x = 0-0.3$ [6], explaining the observed reduction in the FE distortion in the AFM phase. In this paper, we investigate the spin-phonon coupling and related properties through detailed THz, far-infrared (FIR), and Raman spectroscopic studies of SrMnO₃ and combine them with thorough investigations of transport and dielectric properties.

II. EXPERIMENTAL DETAILS

The tolerance factor of SrMnO₃ is very close to unity ($\tau = 1.05$) and therefore it can be synthesized in both cubic and hexagonal crystal structures depending on the growing procedure [9]. We initially prepared the hexagonal SrMnO₃ powder from a stoichiometric mixture of SrCO₃ and Mn₂O₃

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by annealing in air at 1150 °C for 50 h and at 1000 °C for 24 h. Then we pelletized the hexagonal SrMnO₃ with a small amount of PVA and annealed at 1000 °C for 55 h. Afterwards, pellets of the single-phase cubic SrMnO₃ were prepared in two steps [10]: First, we annealed the pellets of hexagonal 4H-SrMnO₃ at 1500 °C for 8 hours in an Ar flow with the heating/cooling rate of 300 °C/min. The weight loss after the first step gave the composition of SrMnO_{2.53(2)}. During the second step, we oxidized the obtained SrMnO_{2.53} sample in air at 350 °C for 15 h. The weight gain after the second step gave the composition of SrMnO_{2.99(2)}. The density of the ceramics was measured to be 5.50(2) g cm⁻³; it is about 97.0% of the powder density, and about 95.8% of the theoretical XRD density.

The phase purity of the cubic SrMnO₃ ceramics was checked by x-ray diffraction and no contamination by the hexagonal phase or by other second phases was discovered. We used the diffractometer Bruker D8 DISCOVER equipped with rotating Cu anode [$\lambda(\text{CuK}\alpha 1) = 1.540598 \text{ \AA}$; $\lambda(\text{CuK}\alpha 2) = 1.544426 \text{ \AA}$] operating with 12 kW power. A parabolic Göbel mirror on the side of the incident beam and Soller collimator and 200-LiF analyzer on the side of the diffracted beam were used. The crystal structure was measured between 170 and 303 K. The temperature was controlled by a cooling stage Anton Paar DCS 350 and no change of the crystal structure with temperature was observed. The lattice parameter a_0 determined from 220 and 310 Bragg diffractions linearly changed with temperature from 3.7988(3) at 170 K to 3.8062(4) Å at 303 K. We have to stress here that we observed no anomaly in $a_0(T)$ around T_N .

The temperature of the magnetic phase transition was checked using calorimetry. The ceramic pellet was placed in an aluminum pan and measured using a differential scanning calorimeter Perkin Elmer Pyris Diamond DSC. The sample was cooled from 300 K down to 100 K with a cooling rate of 10 K/min. The same rate was used for heating. An anomaly at 233 K corresponding to the AFM phase transition was observed in both cooling and heating curves without any temperature hysteresis (see Fig. 1).

The spectroscopic experiments were performed using a Fourier-transform infrared (IR) spectrometer Bruker IFS 113v equipped with a helium-cooled bolometer (operating temperature 1.6 K) as a detector and a custom-made time-domain THz

spectrometer [11]. In both experiments, Optistat CF cryostats (Oxford Instruments) with polyethylene (far IR) or Mylar (THz) windows were used for measurements in the 10–300 K temperature range. In the THz spectrometer, a femtosecond Ti:sapphire laser oscillator (Coherent, Mira) produces a train of femtosecond pulses which generates linearly polarized broadband THz pulses in a photoconducting switch TeraSED (Giga-Optics). A gated detection scheme based on electro-optic sampling with a 1 mm thick [110] ZnTe crystal as a sensor allows us to measure the time profile of the electric field of the transmitted THz pulse (see Ref. [11] for further details).

Ceramic pellets were carefully polished using diamond paste in order to obtain a flat surface with an optical quality. For IR studies, the sample was glued on a circular metallic aperture with a diameter of 5 mm. The sample IR reflectivity was normalized by the reflectivity of a gold mirror sputtered on polished glass, which was glued on the similar aperture. An optical cryostat allowed us to move the sample holder at all temperatures, so we have measured the sample and reference spectra at each temperature. For the time-domain THz transmission experiments we prepared a polished plane-parallel plate of ceramics with thickness of 50 μm.

IR reflectivity and THz complex permittivity spectra were carefully fitted assuming the dielectric function in the form of sum of classical three-parameter damped oscillators [12]

$$\varepsilon^*(\omega) = \varepsilon_\infty + \sum_{j=1}^n \frac{\Delta\varepsilon_j \omega_{\text{TO}j}^2}{\omega_{\text{TO}j}^2 - \omega^2 + i\omega\gamma_{\text{TO}j}}, \quad (1)$$

where $\omega_{\text{TO}j}$, $\gamma_{\text{TO}j}$, and $\Delta\varepsilon_j$ denote the eigenfrequency, damping, and dielectric strength of the j th transversal optic (TO) polar phonon. $\varepsilon^*(\omega)$ is related to the reflectivity $R(\omega)$ of the bulk sample by

$$R(\omega) = \left| \frac{\sqrt{\varepsilon^*(\omega)} - 1}{\sqrt{\varepsilon^*(\omega)} + 1} \right|^2. \quad (2)$$

The high-frequency permittivity $\varepsilon_\infty = 7.6$ given by electronic absorption processes was obtained from the room-temperature frequency-independent reflectivity tails above the phonon frequencies. The temperature dependence of this quantity was neglected, consistent with its behavior in other related perovskite dielectrics [13].

For Raman studies, a Renishaw RM 1000 Micro-Raman spectrometer equipped with a CCD detector and a Linkam THMS 600 temperature cell was used. The experiments were performed in a backscattering geometry in the 100–2000 cm⁻¹ range. A He-Ne laser with the wavelength 633 nm was used.

The magnetic susceptibility data were collected with a Quantum Design (MPMS) superconducting quantum interference device when the applied magnetic field was 100 Oe. The thermoelectric power and thermal conductivity measurements were carried out between 3.5 and 320 K using a close-cycle refrigerator. The four-point steady-state method was applied in order to eliminate thermal resistances between sink and heater; the electrical contacts were realized using a silver paint. The experimental setup was checked using reference samples. For more details we refer to Ref. [14].

Dielectric measurements in the frequency range from 1 MHz to 1.8 GHz were performed using a computer-controlled dielectric spectrometer equipped with an Agilent

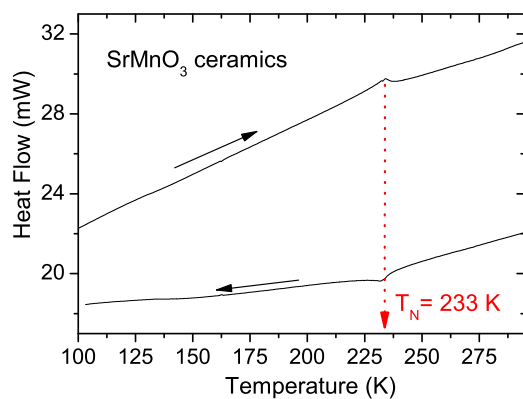


FIG. 1. (Color online) Heat flow measured on cooling and heating. It shows an anomaly near the antiferromagnetic phase transition at $T_N = 233 \text{ K}$ without any thermal hysteresis.

4291B impedance analyzer, Novocontrol BDS 2100 coaxial sample cell, and Sigma System M18 temperature chamber (operating range of 100–500 K). The dielectric parameters were calculated taking into account the electromagnetic field distribution in the sample.

III. CALCULATIONAL DETAILS

First-principles calculations were performed using density-functional theory within the generalized gradient approximation GGA+ U method with the Perdew-Becke-Erzenhof parametrization as implemented in the Vienna *ab initio* Simulation Package (VASP 4.6). Details are described in Ref. [8]. The phonon frequencies depend on the choice of the lattice constant and the value of on-site Coulomb interaction U_{eff} . With $U_{\text{eff}} = 2.3$ eV, the zero-temperature phonon frequencies computed for antiferromagnetic spin ordering at $a_0 = 3.825$ Å, intermediate between the computed lattice constant and the theoretical lattice constant, are in good agreement with the low-temperature experimental values. We note a previous first-principles calculation of phonons at the experimental lattice constant $a_0 = 3.806$ Å yielded good agreement for the TO2 frequency [18]; however, this is not inconsistent as the latter calculations did not include spin polarization. The temperature-dependent spin correlation ($\langle S_i S_j \rangle$) was calculated using mean-field theory with the exchange constant computed at $a_0 = 3.825$ Å and from this the temperature-dependent phonon frequencies are obtained using the spin-phonon parametrization of Ref. [1].

IV. RESULTS

A. IR spectroscopy studies

FIR reflectivity spectra of cubic SrMnO₃ taken at various temperatures down to 10 K are shown in Fig. 2(a). Three polar optical modes (symmetry F_{1u}) typical of the cubic $Pm\bar{3}m$ perovskite structure are seen. The lowest-frequency TO1 phonon undergoes a remarkable temperature-induced shift of its frequency ω_{TO1} . It increases by 18% on cooling [Fig. 2(b)] and therefore its dielectric strength $\Delta\epsilon_1$ decreases by 42% (from 124 to 87) with decreasing temperature. The dielectric strength of the other two phonons is small ($\Delta\epsilon_2 + \Delta\epsilon_4 = 16$) and temperature independent; therefore the static phonon permittivity $\epsilon'(0) = \sum \Delta\epsilon_j + \epsilon_\infty$ exhibits decrease by 32% on cooling [see Fig. 2(c)]. The change in $\Delta\epsilon_j$ follows from the requirement that the plasma frequency $\Omega_{pj} = \sqrt{\Delta\epsilon_j \omega_{\text{TO}j}}$ of the j th uncoupled phonon should be temperature independent. Indeed, examination of the spectra shows that all the plasma frequencies are temperature independent within experimental error [see Fig. 3(a)]. Sakai *et al.* [6] observed different behavior in the SrMnO₃ single crystal, namely decrease of Ω_{p1} and simultaneous increase of Ω_{p2} . This means that the plasma frequency transfers from the TO1 to the TO2 mode, which is a signature of their mutual coupling. This mode coupling is caused by the fact that $\omega_{\text{TO1}} = 180$ cm⁻¹ and $\omega_{\text{TO2}} = 190$ cm⁻¹ are very close in single crystals at low temperatures, while in the investigated ceramics we found the TO1 mode to be less stiffened ($\omega_{\text{TO1}} = 164$ cm⁻¹) and therefore it is less coupled to TO2. Nevertheless, we observed a large enhancement of TO1 phonon damping near and above

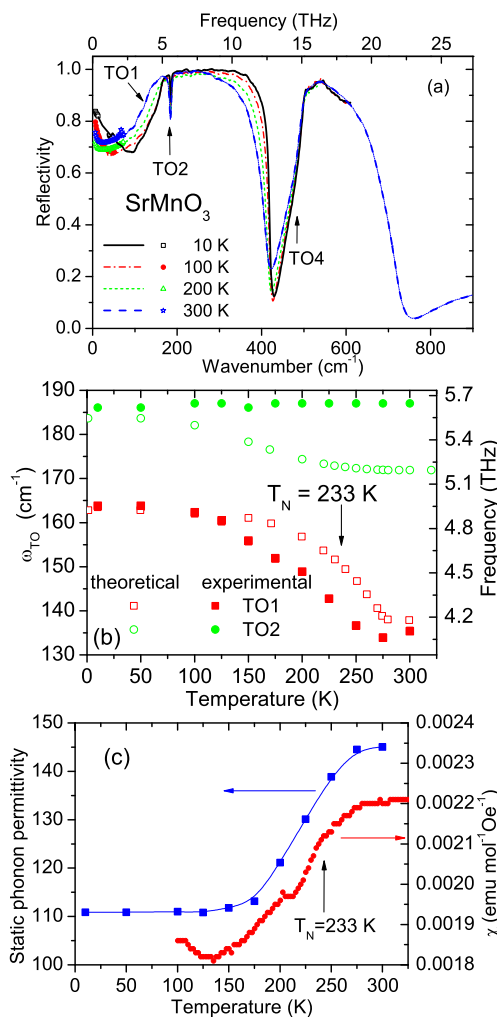


FIG. 2. (Color online) (a) Infrared reflectivity spectra at various temperatures. Frequencies of all three polar phonons are marked by arrows (TO3 is silent). (b) Temperature dependence of TO1 and TO2 phonon frequencies obtained from the fits of IR reflectivity (solid symbols) and first-principles calculations (open symbols). (c) Temperature dependence of the static phonon permittivity obtained from the sum of all phonon and electronic ($\epsilon_\infty = 7.6$) contributions (left scale). Temperature dependence of the static magnetic susceptibility (right scale).

T_N [see Fig. 3(b)]. The discrepancy of ω_{TO1} in the ceramics and crystal can be attributed to different oxygen content in both samples. Note, we annealed the ceramics at 350 °C in air and at ambient pressure, while the crystal was annealed at 480 °C in oxygen atmosphere at pressure of 6.5 GPa [5].

The temperature dependence of the static permittivity $\epsilon'(0)$ obtained from IR spectra is shown in Fig. 2(c). $\epsilon'(0)$ consists of the sum of dielectric contributions of all three polar phonons and electrons. The decrease of $\epsilon'(0)$ by 32% on cooling below T_N follows from Lydanne-Sachs-Teller relation $\frac{\epsilon'(0)}{\epsilon_\infty} = \Pi \frac{\omega_{\text{LO}j}^2}{\omega_{\text{TO}j}^2}$ due to the ω_{TO1} stiffening on cooling (longitudinal phonon frequency $\omega_{\text{LO}j}$ is usually temperature independent). Note that the temperature change of $\epsilon'(0)$ is one order of magnitude larger than that found in EuTiO₃ [15], which is assumed to be a material with very strong spin-phonon coupling. Note as well

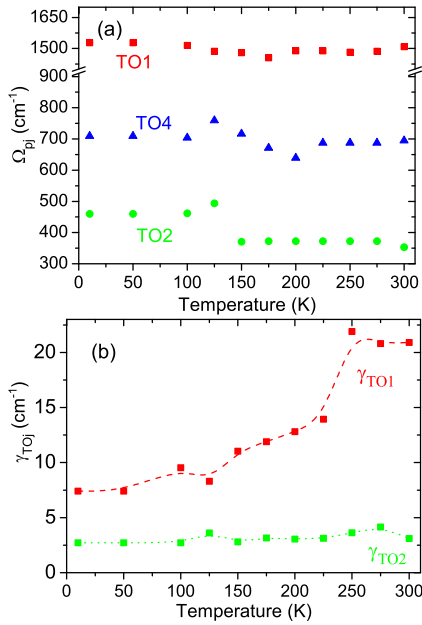


FIG. 3. (Color online) (a) Temperature dependence of experimental plasma frequencies $\Omega_{pj} = \sqrt{\Delta\varepsilon_j}\omega_{\text{TO}j}$ of all the polar phonons. (b) Temperature dependence of TO1 and TO2 phonon damping obtained from the fits of IR spectra. Lines are guides for the eye.

that the static magnetic susceptibility χ exhibits temperature dependence similar to that of $\varepsilon'(0)$ [see Fig. 2(c)]. We have measured $\chi(T)$ up to 500 K and from its fit by a Curie-Weiss law we have obtained the Curie-Weiss temperature $\Theta \cong -2300$ K. This gives evidence about strong magnetic correlations above T_N . Similar $\chi(T)$ behavior was reported by Belik *et al.* [10].

Note that $\chi(T)$ starts to decrease already near 270 K [Fig. 2(c)], 40 K above T_N . TO1 phonon frequency exhibits a minimum as well near 270 K [Fig. 2(b)]. This can be caused by short-range magnetic correlations above T_N , hints of which are also seen in the temperature dependence of the thermal conductivity κ (see discussion in Sec. IV C).

The experimentally observed TO1 phonon frequency and its temperature dependence correspond very well to the theoretical prediction obtained from first-principles calculations [see Fig. 2(b)]. Our calculations show that the TO1 phonon eigenvector corresponds to a Slater-type vibration, i.e., to the Mn vibrations against oxygen octahedra. In Fig. 3(a) we see that this mode has the highest plasma frequency Ω_{P1} , which gives experimental evidence that the TO1 phonon is the Slater mode [16]. The theoretical TO2 mode frequency corresponds well to the experimental value at 10 K, but unlike the experimental mode, it softens slightly with increasing temperature and at room temperature it is 10% lower than the experimental value. However, this behavior is sensitive to the choice of lattice constant and the temperature dependence of the TO2 mode is reduced in calculations for which the chosen lattice constant is increased. Note that $\omega_{\text{TO}2}$ is experimentally determined very precisely (± 1 cm^{-1}), because its damping is very low [see Figs. 2(a) and 3(b)]. A temperature-independent $\omega_{\text{TO}2}(T)$ like that shown in Fig. 2(b) was reported by Sakai *et al.* [6].

Sacchetti *et al.* [17] investigated FIR reflectivity spectra of cubic and hexagonal SrMnO_3 at 100 and 300 K and obtained the same result as found here, but they did not present detailed

temperature dependence of the phonon frequencies. Nevertheless, they have shown that 4H and 6L hexagonal phases of SrMnO_3 have 12 and 14 IR-active modes, respectively [17]. We found only 3 polar phonons in the whole experimental temperature range. This confirms that our SrMnO_3 ceramics is not contaminated by any detectable secondary hexagonal phase.

B. Raman spectroscopy studies

Micro-Raman spectra were measured down to 80 K. SrMnO_3 crystallizes in the cubic $Pm\bar{3}m$ structure, where all the phonons should be Raman inactive and only 3 F_{1u} symmetry modes are IR active [16]. In spite of this fact, three broad bands are seen in the room-temperature Raman spectrum (see Fig. 4). These bands come, as they do in SrTiO_3 [19], from Raman scattering of higher order, i.e., from multiphonon summation processes. The bands split on cooling, because the phonon damping decreases towards low temperatures. Several new modes also appear outside of the region of the original three bands. The experimental Raman spectrum measured at 80 K and its fit with assigned mode frequencies are shown in Fig. 5. The frequencies of the peaks at 192 and 508 cm^{-1} correspond to TO2 and TO4 frequencies (in our assignment, the TO3 mode is silent in IR and Raman spectra of perovskites with $Pm\bar{3}m$ structure). However, polar TO2 and TO4 modes are forbidden in Raman spectra of the cubic structure. This means that the Raman scattering spectra give evidence of locally broken cubic structure and center of symmetry below the magnetic phase transition temperature, although our x-ray diffraction experiment performed down to 170 K did not reveal any change of the macroscopic symmetry. Similar magnetically induced changes of the phonon selection rules were recently reported in various transition-metal monoxides and chromium spinels [20]. In that work, structural investigations did not reveal any changes. However, IR spectra resolved a remarkable phonon splitting below T_N . This was explained by the exchange coupling which slightly distorts

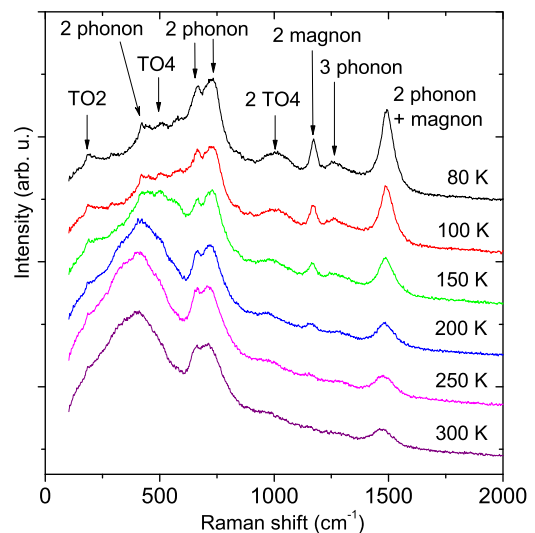


FIG. 4. (Color online) Micro-Raman spectra of SrMnO_3 ceramics taken at various temperatures. The peaks seen at 80 K are assigned.

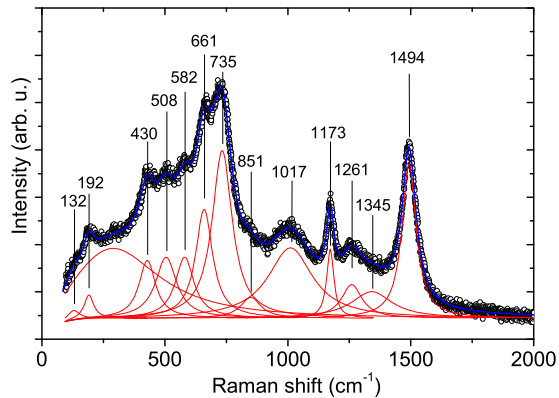


FIG. 5. (Color online) Raman scattering spectrum taken at 80 K and its decomposition into independent damped harmonic oscillators. Frequencies of the Raman modes are marked.

the local cubic symmetry of the crystals and activates new phonons in the spectra [20].

There are several other new Raman bands activated below T_N . The frequency of the band seen at 1017 cm^{-1} corresponds exactly to twice the TO4 mode frequency. A sharp band appears below T_N at 1173 cm^{-1} . This is most probably a two-magnon scattering coming from magnons at the Brillouin zone boundary. Two other strong peaks are seen near 1300 and 1500 cm^{-1} . These come from multiphonon and/or phonon-magnon scattering. In this summation process mainly phonons and magnons with maximal density of states contribute, i.e., with wave vectors from the Brillouin zone boundary. Similar multiphonon and multimagnon Raman bands arising below T_N were observed in BiFeO_3 [21,22].

The newly activated Raman modes cannot come from a secondary hexagonal phase, because the hexagonal phase does not have any phonons above 800 cm^{-1} and our low-frequency modes also do not correspond to phonons of hexagonal SrMnO_3 [17,23]. Moreover, 4H hexagonal SrMnO_3 exhibits structural and magnetic phase transitions already around 380 K and 280 K, respectively [24].

C. Dielectric and conductivity studies

The static permittivity $\epsilon'(0)$ shown in Fig. 2(c) is given by phonon and electron contributions and it corresponds to THz experimental values measured between 100 and 300 K. However, values of the megahertz permittivity are two orders of magnitude higher [see Fig. 6(a)]. This is caused by a non-homogeneous conductivity of the sample in the ceramic grains and grain boundaries, which is responsible for the creation of internal barrier layer capacitors on the grain boundaries. This mechanism is responsible for a “giant” effective permittivity in many dielectric or multiferroic materials [25–27].

The real part of the conductivity $\sigma'(\omega)$ exhibits strong frequency dependence typical for hopping processes [28]. Its low-frequency part is almost frequency independent and it corresponds to a static (dc) conductivity of the percolated grain boundaries. The high-frequency part of $\sigma'(\omega)$ increases with frequency. However, it shows a plateau between 0.1 and 1 THz. Then $\sigma'(\omega)$ again increases towards higher frequencies. The plateau THz conductivity value corresponds

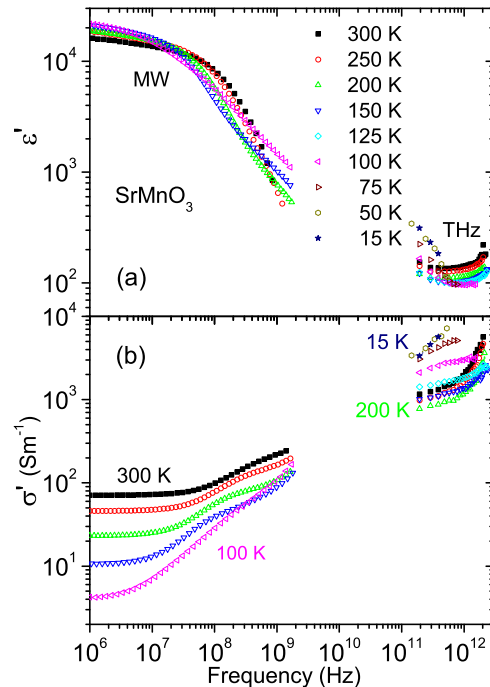


FIG. 6. (Color online) Frequency dependence of the microwave and THz (a) dielectric permittivity and (b) conductivity measured at various temperatures. Note that the MW data were obtained only above 100 K.

to the conductivity in the ceramic grains, while the rising $\sigma'(\omega)$ above 1 THz is caused by a phonon absorption.

Unfortunately, we could not study grain-size dependence of the conductivity, because we could not prepare ceramics with various grain sizes. As mentioned already in Sec. II, we had to transform the initial hexagonal ceramics to the cubic phase by 8 hour annealing at 1500°C followed by rapid quenching of the ceramics. The grains grow at such high temperature that we could not control their size. We should mention that Sakai’s single crystal was also conducting, and therefore they published only 1 GHz permittivity at 4 K. No radio-frequency or microwave data of SrMnO_3 taken at higher temperatures were published by Sakai *et al.* or by other authors.

The frequency-dependent conductivity $\sigma'(\omega)$ exhibits a very interesting temperature dependence [see Fig. 6(b) and inset of Fig. 7]. The static and low-frequency $\sigma'(\omega)$ exhibits classical semiconductor behavior; i.e., it decreases on cooling. However, the THz $\sigma'(\omega)$ exhibits complex temperature behavior. Its value decreases on cooling from 300 K to 200 K, but on further cooling it increases and at 15 K reaches almost one order of magnitude higher values than that at 200 K. The former decrease of the THz conductivity on cooling is caused by a reduced phonon damping at low temperatures and by a corresponding lower phonon absorption in the THz region. However, on further cooling below 200 K the mean-free path of charge carriers in the ceramic grains dramatically increases and therefore also the THz $\sigma'(\omega)$ increases. It can be caused by the so called magnon drag effect [29], when magnons promote the high-frequency conductivity. The THz conductivity and permittivity spectra were possible to fit together with the IR reflectivity spectra using a sum of damped oscillators from

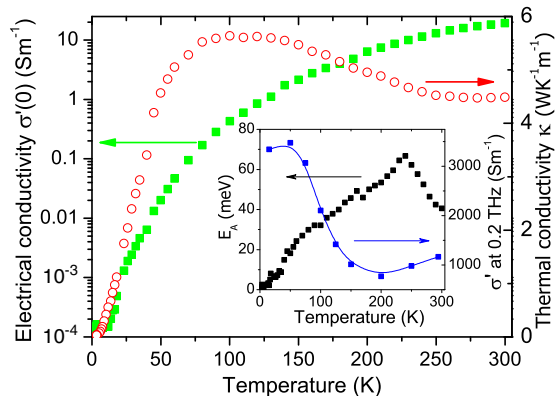


FIG. 7. (Color online) Temperature dependence of the static electrical conductivity $\sigma'(0)$ and thermal conductivity κ . Temperature dependence of the activation energy E_a of the dc conductivity and conductivity σ' measured at 0.2 THz are shown in the inset.

Eq. (1). The high-frequency hopping conductivity is seen at low temperatures as a peak near 30 cm^{-1} in the optical conductivity $\sigma'(\omega)$; see Fig. 8. The higher frequency peaks correspond to the polar phonons.

In order to determine accurate chemical composition, specifically the concentration of oxygen vacancies and consequently of Mn^{3+} species, we have measured the thermoelectric power. Using the standard configuration entropy approach [30], we have determined the concentration of Mn^{3+} in $\text{SrMn}^{4+}\text{O}_3$ using the room-temperature thermoelectric power ($S \sim -350 \mu\text{V K}^{-1}$) as 2% of all Mn^{3+} species.

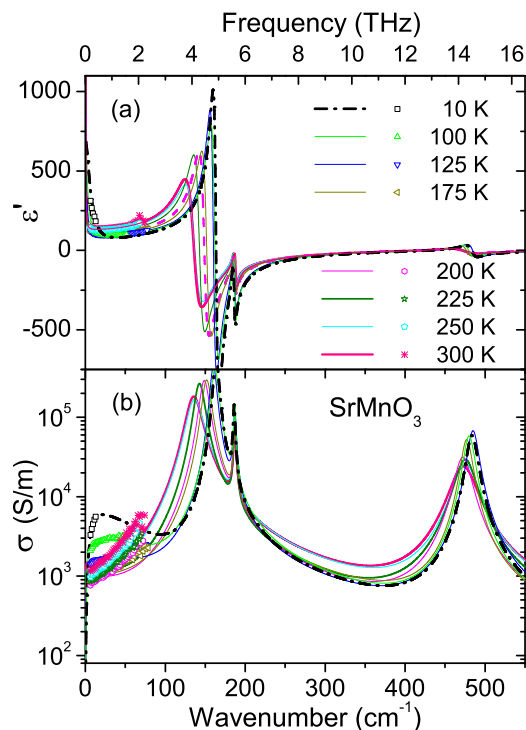


FIG. 8. (Color online) (a) Real part of the complex dielectric function and (b) optical conductivity in SrMnO_3 obtained from the fits of the THz and IR spectra measured at various temperatures. At low frequencies and low temperatures arises a peak in the conductivity, which we fitted using a highly damped oscillator.

This results in the chemical formula of our ceramic sample $\text{Sr}^{2+}\text{Mn}_{0.98}^{4+}\text{Mn}_{0.02}^{3+}\text{O}_{2.99}^{2-}$. The same composition was obtained independently by measurement of the sample weight changes due to oxidation during annealing [10].

In addition, we have measured the temperature dependence of the thermal conductivity κ down to 4 K. These data are shown together with the local activation energy E_a of $\sigma'(0)$ in Fig. 7. Most typically, the thermal conductivity of a nonmetallic material is dominated by the phononic part, which we assumed to be true for the case of SrMnO_3 . The temperature dependence of κ is then governed by the specific heat, sound velocity, and phonon mean-free path. These are decisively influenced by various scattering mechanisms. Considering the Debye temperature $\Theta_D \sim 400 \text{ K}$ of SrMnO_3 we anticipate the “classic” hyperbolic increase of κ below room temperature, reflecting the dissipative umklapp phonon-phonon scattering. At low temperatures this is followed by the decrease critically limited by the grain boundary scattering. As we are dealing with a magnetic material, we should anticipate the phonon scattering on magnons, which should reduce κ . This is in fact observed in SrMnO_3 ; $\kappa(T)$ is temperature independent down to $\sim T_N$ and only a very moderate increase with decreasing temperature to 100 K is observed. Below this temperature κ decreases due to the decreasing specific heat. Let us note that similar behavior was recently reported by Suzuki *et al.* [31], who have shown that the observed $\kappa(T)$ is dominated by acoustic phonons. We conclude that based on the temperature variation of κ the phonons are critically scattered not only by magnons below T_N , but also by paramagnons above T_N . Contrary to the complex temperature dependence of κ , the static electrical conductivity $\sigma'(0)$ (Fig. 7) exhibits monotonic decrease from 20 S m^{-1} (at 300 K) down to 10^{-4} S m^{-1} without apparent anomalies. Nevertheless, detailed evaluation of the temperature dependence of $\sigma'(0)$ reveals a maximum of the local activation energy E_a near T_N , underlining the interrelation between the magnetic order and charge carrier transport. The decrease of $E_a(T)$ to zero suggests hopping as the most likely mechanism of charge carrier transport. The fact that the T_N is reflected by the large, broad but distinct anomaly in electric transport gives evidence that the charge, lattice, and magnetic degrees of freedom are strongly coupled in SrMnO_3 .

V. CONCLUSION

First-principles calculations predicted a large stiffening of TO1 phonon frequency below T_N , which we experimentally confirmed. In consequence, the static phonon permittivity drops by 32%. Spin-phonon coupling also influences the change of the local crystal symmetry, which allows activation of the polar phonons in Raman scattering spectra. Moreover, multiphonon and multimagnon peaks in the Raman spectra appear, sharpen, and split on cooling. The MHz permittivity reaches giant values due to the conductivity of the ceramic grains. This comes from a small nonstoichiometry of the ceramics with chemical formula $\text{Sr}^{2+}\text{Mn}_{0.98}^{4+}\text{Mn}_{0.02}^{3+}\text{O}_{2.99}^{2-}$. The sample nonstoichiometry originates from annealing at 1500°C during the ceramic preparation and its subsequent fast quenching to room temperature. Unfortunately, this procedure is necessary for stabilization of the cubic perovskite structure in SrMnO_3 , because the hexagonal structure of SrMnO_3 is

otherwise more stable. Sample annealing performed in air at 350 °C significantly modifies the oxygen content of the sample, which changes from SrMnO_{2.53} to SrMnO_{2.99}, but unfortunately it was not possible to obtain a fully stoichiometric sample. On one hand, the static conductivity always decreases on cooling because it is influenced by the semiconducting grain boundaries. On the other hand, the mean-free path of charge carriers in ceramic grains increases on cooling, and therefore also the THz conductivity increases with lowering temperature.

Our data show exceptionally high spin-phonon coupling in SrMnO₃, which could be used for induction of the ferroelectric phase in strained thin films or doped bulk samples. Nevertheless, since good insulating behavior of the samples is necessary

for possible multiferroic applications, perfect stoichiometry of SrMnO₃ is required. Annealing at a high hydrostatic pressure in oxygen atmosphere could be a way to prepare highly resistive samples with strong magnetoelectric coupling.

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